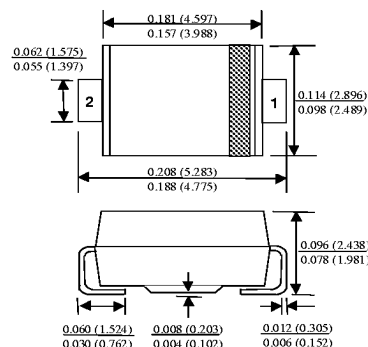
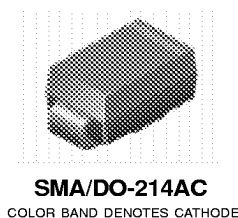


ES1A - ES1D

Features

- For surface mount applications.
- Glass passivated junction.
- Low profile package.
- Easy pick and place.
- Built-in strain relief.
- Superfast recovery times for high efficiency.



1.0 Ampere Superfast Rectifiers

Absolute Maximum Ratings*

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
I_O	Average Rectified Current @ $T_A = 120^\circ\text{C}$	1.0	A
$i_{f(\text{surge})}$	Peak Forward Surge Current 8.3 ms single half-sine-wave Superimposed on rated load (JEDEC method)	30	A
P_D	Total Device Dissipation Derate above 25°C	1.47 11.76	W mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient**	85	$^\circ\text{C/W}$
$R_{\theta JL}$	Thermal Resistance, Junction to Lead**	35	$^\circ\text{C/W}$
T_{stg}	Storage Temperature Range	-50 to +150	$^\circ\text{C}$
T_J	Operating Junction Temperature	-50 to +150	$^\circ\text{C}$

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

**Device mounted on FR-4 PCB 0.013 mm.

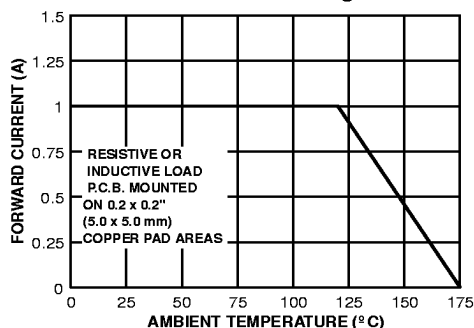
Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

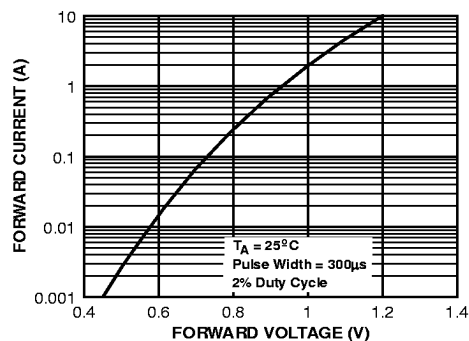
Parameter	Device				Units
	1A	1B	1C	1D	
Peak Repetitive Reverse Voltage	50	100	150	200	V
Maximum RMS Voltage	35	70	105	140	V
DC Reverse Voltage (Rated V_R)	50	100	150	200	V
Maximum Reverse Current @ rated V_R $T_A = 25^\circ\text{C}$	5.0				μA
$T_A = 100^\circ\text{C}$	100				μA
Maximum Reverse Recovery Time $I_F = 0.5\text{ A}$, $I_R = 1.0\text{ A}$, $I_{RR} = 0.25\text{ A}$	15				nS
Maximum Forward Voltage @ 1.0 A	0.92				V
Typical Junction Capacitance $V_R = 4.0\text{ V}$, $f = 1.0\text{ MHz}$	7.0				pF

Typical Characteristics

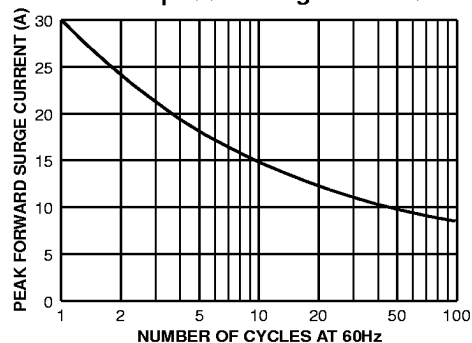
Forward Current Derating Curve



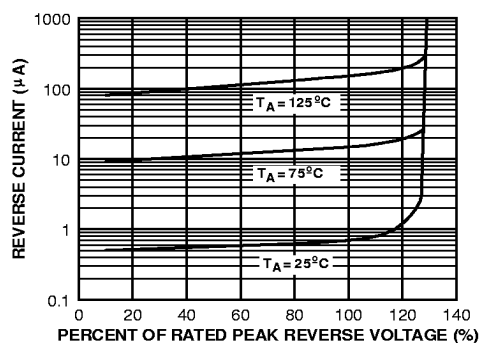
Forward Characteristics



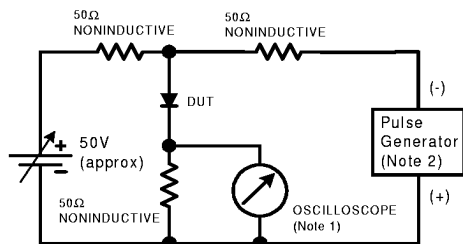
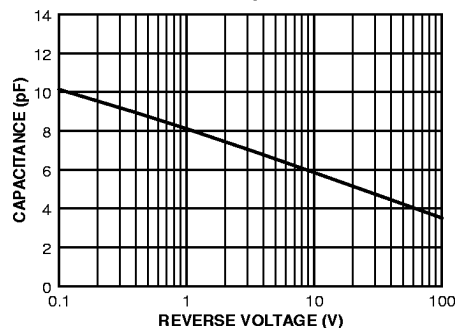
Non-Repetitive Surge Current



Reverse Characteristics



Junction Capacitance



- NOTES:
1. Rise time = 7.0 ns max; Input impedance = 1.0 megaohm 22 pf.
2. Rise time = 10 ns max; Source impedance = 50 ohms.

Reverse Recovery Time Characteristic and Test Circuit Diagram

